

# FR201G - FR207G-STR

# GLASS PASSIVATED JUNCTION FAST RECOVERY RECTIFIERS

**PRV : 50 - 1000 Volts**

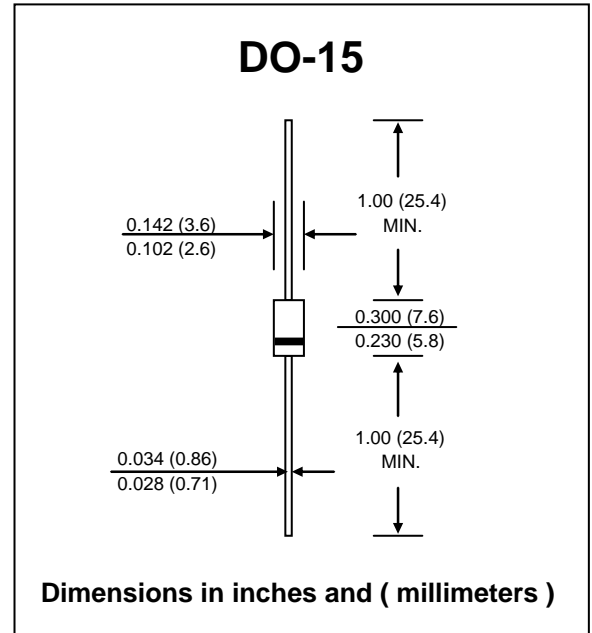
**Io : 2.0 Amperes**

### FEATURES :

- \* Glass passivated junction chip
- \* High current capability
- \* High reliability
- \* Low reverse current
- \* Low forward voltage drop
- \* Fast switching for high efficiency
- \* **Pb / RoHS Free**

### MECHANICAL DATA :

- \* Case : DO-15 Molded plastic
- \* Epoxy : UL94V-0 rate flame retardant
- \* Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
- \* Polarity : Color band denotes cathode end
- \* Mounting position : Any
- \* Weight : 0.4 gram



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.  
Single phase, half wave, 60 Hz, resistive or inductive load  
For capacitive load, derate current by 20%

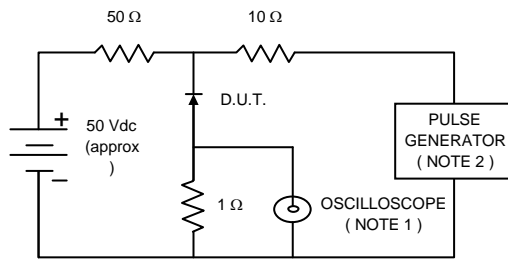
RATING	SYMBOL	FR201G	FR202G	FR203G	FR204G	FR205G	FR206G	FR207G	FR207G-STR	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 75 °C	IF(AV)	2.0								A
Peak Forward Surge Current, 8.3ms Single half sine wave superimposed on rated load (JEDEC Method)	IFSM	75								A
Maximum Peak Forward Voltage at IF = 2.0 A	VF	1.3								V
Maximum DC Reverse Current Ta = 25 °C	IR	10								µA
at Rated DC Blocking Voltage Ta = 100 °C	IR(H)	500								µA
Maximum Reverse Recovery Time ( Note 1 )	Trr	150			250		500		250	ns
Typical Junction Capacitance ( Note 2 )	CJ	15								pf
Junction Temperature Range	TJ	- 65 to + 150								°C
Storage Temperature Range	TSTG	- 65 to + 150								°C

**Notes :**

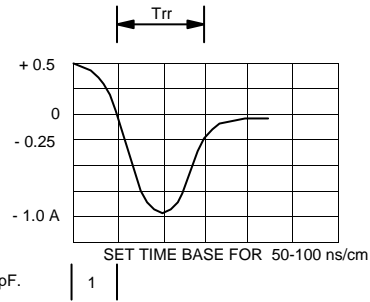
- ( 1 ) Reverse Recovery Test Conditions :IF = 0.5 A, IR = 1.0 A, Irr = 0.25 A.
- ( 2 ) Measured at 1.0 MHz and applied reverse voltage of 4.0 Vdc

**RATING AND CHARACTERISTIC CURVES ( FR201G - FR207G-STR )**

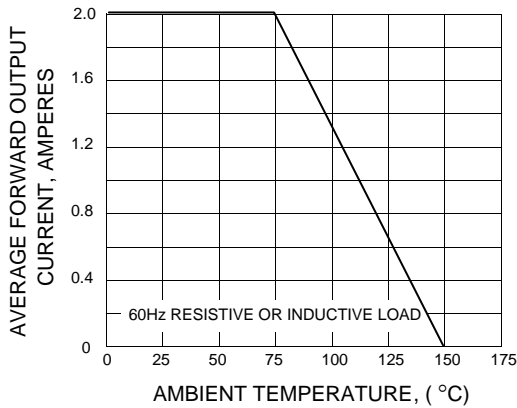
**FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**



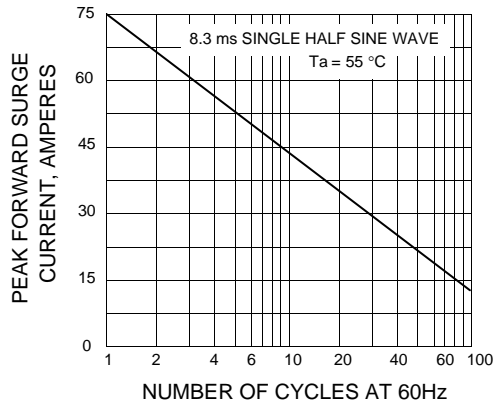
NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.  
2. Rise time = 10 ns max., Source Impedance = 50 ohms.  
3. All Resistors = Non-inductive Types.



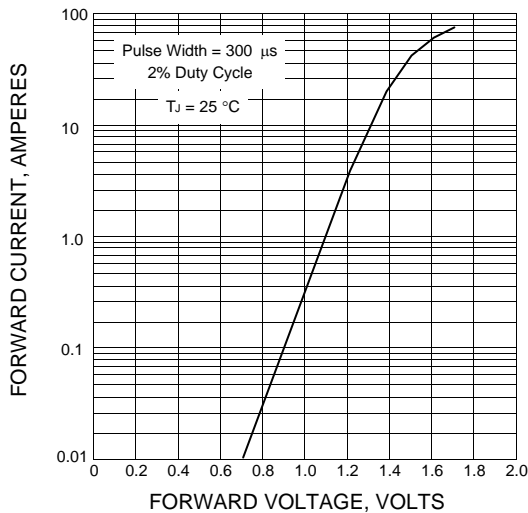
**FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT**



**FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG.4 - TYPICAL FORWARD CHARACTERISTICS**



**FIG.5 - TYPICAL REVERSE CHARACTERISTICS**

